# PRODUCT OVERVIEW

MediaTek MT7686D is based around a highly integrated chipset containing a microcontroller unit (MCU), a low power 1x1 11n single-band Wi-Fi subsystem and a power management unit (PMU). The microcontroller unit is an ARM Cortex-M4 processor with floating point, integrated with up to 4MB PSRAM and up to 4MB flash memory.

The Wi-Fi subsystem contains 802.11b/g/n radio, baseband and MAC designed for low power and high throughput application development. It also contains a 32-bit RISC CPU that could fully offload the application processor.

MT7686 also supports interfaces including UART, I2C, SPI, I2S, PWM, SDIO and ADC.
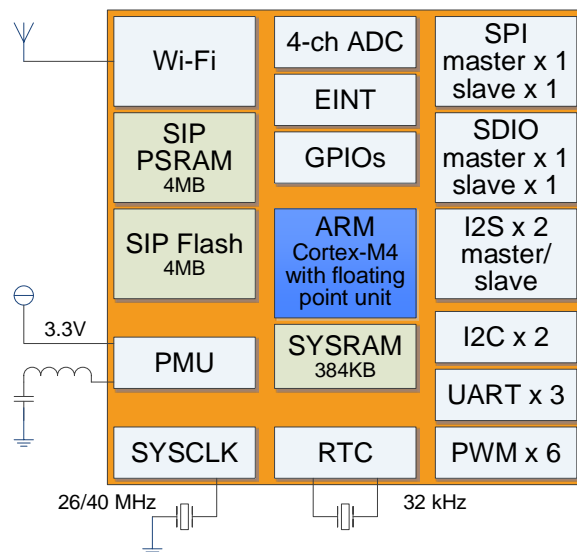
BENEFITS

- Highly integrated with RF, MCU and memory
- Low power mode with RTC

TARGET APPLICATIONS

- Home appliances
- Home automation
- Smart gadget
- IoT bridge
- Multi-cloud connectivity

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FEATURES

Wi-Fi

- IEEE 802.11 b/g/n (2.4GHz, 1x1)
- Supports 20MHz, 40MHz bandwidth in 2.4GHz band
- Wi-Fi security WEP/WPA2/WPS
- SoftAP, sniffer
- Dynamically switching between STA and SoftAP modes at runtime
- MediaTek smart connection
- Multi-cloud connectivity
- RX antenna diversity
- Wi-Fi and Bluetooth LE coexistence
- Integrated Balun, PA/LNA
- Optional external LNA and PA support

Microcontroller subsystem

- 192MHz ARM® Cortex®-M4 with FPU
- 16 DMA channels
- 1 RTC timer, 1 64-bit and 5 32-bit general purpose timers
- Hardware DFS from 3MHz to 192MHz
- Development support: SWD, JTAG
- Crypto engine
  - AES 128/192/256 bits
  - DES, 3DES
  - MD5, SHA-1/224/256/384/512
- True random number generator
- JTAG password protection

Memory

- Up to 384KB SRAM, with zero-wait state, max frequency 96MHz
- Up to 32KB L1 cache, with high hit rate, zero-wait state, max frequency 192MHz
- Embedded 32Mbits flash, with less than 0.1µA (typical) and 80MHz maximum frequency deep power-down current
- Embedded 32Mbits pseudo SRAM with half sleep mode current: 10µA (PASR 1/8 at 25°C 1x Refresh) and 96MHz maximum frequency

Communication interfaces

- 1 SDIO 2.0 master and 1 SDIO 2.0 slave
- 2 I2C (3.4Mbps) interfaces
- 3 UARTs (3Mbps)

- 1 SPI master and 1 SPI slave (both SCKs are up to 48MHz, quad mode)
- 2 I2S interfaces
  - 1 16/24-bit, master/slave mode; 1 16-bit, master/slave mode with TDM
  - 2 TX/RX channels with 16/24/48/96/192 kHz and 11.025kHz, 22.05kHz, 44.1kHz frequencies
- 6 PWM channels
- 21 GPIOs (fast IOs, 5V-tolerant)
- 6 channel 12-bit AUXADC

Power management

- Integrated DC-DC
- Power input
  - V_{RTC}: from 1.62V to 3.63V
  - V_{PMU} / V_{RF}: 3.3V (+/-10%)
  - V_{IO}*: 1.8V/2.8V/3.3V (+/-10%)
- Off mode: <0.5µA
- Retention mode (with RTC)
  - <2µA (RTC only)
  - ~4.4µA with 8KB RAM sleep mode
- Deep sleep mode (with external 32kHz clock)
  - 70µA with 0KB RAM sleep mode
  - 102µA with 384KB RAM sleep mode
- G-band RX power: 59 mA
- G-band TX power
  - FPA: 268mA 19dBm CCK
  - HPA: 203mA 16.5dBm OFDM
- DTIM interval with 32kHz external clock source and 384KB SRAM
  - DTIM=1: 0.75mA
  - DTIM=3: 0.33mA
- Ambient temperature from -40°C to 85°C

Clock source

- 26MHz or 40MHz crystal oscillator
- 32kHz crystal oscillator or internal 32kHz RC for RTC

Package

- 6-mm x 6-mm x 0.9-mm 48-pin QFN with 0.4-mm lead pitch

Note:
- The power consumption data is measured at 25°C.